

## APPLICATION NOTE

# CROSSTALK BEHAVIOUR OF ITA25 IN RS232 TRANSMISSION

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#### **I - INTRODUCTION**

Crosstalk is a digital interference phenomenon between data lines. The signal transmission by one data line produces parasitic voltages on nearby channels. These disturbances are due mainly to capacitive coupling or electro magnetic interference. This phenomenon occurs particulary when a great number of lines are located in a small area, notably in the case of multiline protection circuits having a high density.

The decrease of available area and the increase in the number of lines managed by a board forces the use of a single chip configuration to realize the protection function.

The goal of this paper is to quantify the parasitic effect of SGS-THOMSON monolithic protection products.

#### **II - TEST DIAGRAM**

To analyse the crosstalk behavior we will take as an example the most commonly- used interface : RS232.





Figure 1 shows the test circuits used to do the crosstalk measurements.

The equivalent circuits of the drivers and receivers have been determined from the RS232C standard. So the following tests are done with :

R1 + R'1 = 500 Ohms and R2 + R'2 = 3 k Ohms

#### **III - THEORICAL ANALYSIS**

#### Figure 2 : Equivalent diagram



Figure 2 A/ shows the internal circuit diagram of the 8 way protection device ITA25. We see that the cathodes of all channels are common. If we consider the two adjacent lines V1 and V2, we note that when V1 is more positive than V2, both channels are connected through the off state capacitance of one of the diodes (see fig.2 B/).

We have the same phenomenon when V2 is more positive than V1 (see fig.2 C/).

So the equivalent circuit of both driver and receiver lines is given by fig.3. This diagram shows the worse case, because the input resistance of the receiver 2 has not been taken into account and zero line capacitance has been assumed.

The simulation results using this equivalent circuit are given in figure 4.

The capacitance C is equal to 200 pF for a bias voltage of 12 V.









This simulation gives the following parameters :

- VR peak : +/- 11.7 V
- Time constant : 0.2 us

Despite their large amplitude, these peaks would not cause any problems. Their short duration means that they would be filtered out by the RS232 input sampling operation.



## **IV - MEASUREMENTS**





The measurements have been done in the figure 5 configuration. Three cases have been taken into account :

- DRIVER 2 output at -12 V (see fig.6)

- DRIVER 2 output at OV (see fig.7)

- DRIVER 2 output at +12 V (see fig.8)

Figure 6 : Ve/VR with DRIVER 2 voltage = -12 V



## Figure 7 : Ve/VR with DRIVER 2 voltage = 0 V



Figure 8 : Ve/VR with DRIVER 2 voltage = 12 V



The waveforms of figs. 6, 7 and 8 show parasitic overvoltages lower than in the simulation. This is largely due to the presence of line capacitance and a finite input impedance. The duration of the

spikes is similar, so again they would be removed by the RS232 input sampling.

The expanded view of figure 7 given by figure 9 quantifies the duration of the phenomenon.





Figure 9 : Expanded view of Ve/VR with DRIVER 2 output = 0 V

### **V - DISTURBANCE EFFECTS - CONCLUSION**

The measurements described in chapter IV show parasitic overvoltages of +/- 3 V for a duration of about 0.4 us. These will not result in any corruption of data because of input sampling by the RS232 interface.

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